



Title of Change:	NC7SZXX Family Datasheet updates per FPCN22057X and FPCN22090X.	
Effective date:	26 June 2019	
Contact information:	Contact your local ON Semiconductor Sales Office or <david.manley@onsemi.com>	
Type of notification:	This Product Bulletin is for notification purposes only. ON Semiconductor will proceed with implementation of this change upon publication of this Product Bulletin.	
Change Category:	<input type="checkbox"/> Wafer Fab <input type="checkbox"/> Assembly Change <input type="checkbox"/> Test Change <input checked="" type="checkbox"/> Other <u>Datasheet Change</u>	
Change Sub-Category(s):	<input type="checkbox"/> Manufacturing Site Addition <input type="checkbox"/> Material Change <input checked="" type="checkbox"/> Datasheet/Product Doc change <input type="checkbox"/> Manufacturing Site Transfer <input type="checkbox"/> Product specific change <input type="checkbox"/> Shipping/Packaging/Marking <input type="checkbox"/> Manufacturing Process Change <input type="checkbox"/> Other: _____	
Sites Affected:	ON Semiconductor Sites: None	External Foundry/Subcon Sites: None
Description and Purpose:		
<p>This PB is issued to notify customers of the datasheet changes for the NC7SZ family per FPCN22057X and FPCN22090X.</p> <p>Provided here are comparison between the new and old datasheets regarding changing specifications and/or specification conditions.</p> <ul style="list-style-type: none"> • Areas of change are circled red. • Items from the old datasheet that will be changed are highlighted red. • The corresponding value on the new datasheet is highlighted in green. • Areas of change circled in yellow are changes that were found to be needed after the PCN <p>There will be other changes that represent a cleanup and standardization to the datasheet to represent a family oriented specification format. These changes will include forms of the following:</p> <ul style="list-style-type: none"> • Correction of clerical errors such as spelling. • Formatting to create family standards. • Addition of new package types and possible removal of packages no longer available. 		

- Correction to references above recommended voltage rating.

Existing datasheet

Description

The NC7SZXX is a single two-input NAND gate from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 6V, independent of V_{CC} operating voltage.

General Description

The NC7SZXX is a single 3-Input NAND Gate from Fairchild's Ultra High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 7V independent of V_{CC} operating voltage.

Description

The NC7SZXX is a single 2-Input NAND gate with open drain output stage from Fairchild's Ultra-High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 6V independent of V_{CC} operating voltage. The open drain output stage tolerates voltages up to 6V independent of V_{CC} when in the high impedance state.

New

Description

The NC7SZXX is a single two-input NAND gate from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V, independent of V_{CC} operating voltage.

General Description

The NC7SZXX is a single 3-Input NAND Gate from Fairchild's Ultra High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V independent of V_{CC} operating voltage.

Description

The NC7SZXX is a single 2-Input NAND gate with open drain output stage from Fairchild's Ultra-High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V independent of V_{CC} operating voltage. The open drain output stage tolerates voltages up to 5.5V independent of V_{CC} when in the high impedance state.

- Replaced SOT23 package with SC-74A.

Existing datasheet

Ordering Information

Part Number	Top Mark	Package	Packing Method
NC7SZXXM5X	7Z00	5-Lead SOT23, JEDEC MO-178 , 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	Z00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	YY	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	YY	6-Lead, MicroPak2™, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Ordering Information

Part Number	Operating Temperature	Top Mark	Eco Status	Package	Packing Method
NC7SZXXM5X	-40 to +85°C	7Z14	RoHS	5-Lead, SOT23, JEDEC MO-178 , 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	-40 to +85°C	Z14	RoHS	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	-40 to +85°C	B6	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	-40 to +85°C	B6	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

New

Ordering Information

Part Number	Top Mark	Package	Packing Method
NC7SZXXM5X	7Z00	5-Lead SC-74A , 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	Z00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	YY	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	YY	6-Lead, MicroPak2™, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Ordering Information

Part Number	Operating Temperature	Top Mark	Eco Status	Package	Packing Method
NC7SZXXM5X	-40 to +85°C	7Z14	RoHS	5-Lead, SC-74A , 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	-40 to +85°C	Z14	RoHS	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	-40 to +85°C	B6	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	-40 to +85°C	B6	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Adjusted Absolute Maximum Voltage to match new process.

Existing datasheet

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Voltage (V_{IN})	-0.5V to +7.0V
DC Output Voltage (V_{OUT})	-0.5V to +7.0V

New

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +6.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.5	7.0	V
V_{IN}	DC Input Voltage	-0.5	7.0	V
V_{OUT}	DC Output Voltage	-0.5	7.0	V

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.5	6.5	V
V_{IN}	DC Input Voltage	-0.5	6.5	V
V_{OUT}	DC Output Voltage	-0.5	6.5	V

- Replaced SOT23 package with SC-74A.
- Adjusted Power Dissipation to reflect new die.
- Adjusted Thermal Resistance to reflect new die.

Existing datasheet

P_D	Power Dissipation at +85°C	SOT-23		mW
		SC70-5	MicroPak™-6	
		200	150	
		130	120	

New

P_D	Power Dissipation at +85°C	SC-74A		mW
		SC70-5	MicroPak™-6	
		225	190	
		327	327	

Absolute Maximum Ratings (Note 1)		Recommended Operating Conditions (Note 2)	
Supply Voltage (V_{CC})	-0.5V to +6.5V	Supply Voltage Operating (V_{CC})	1.85V to 5.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V	Supply Voltage Data Retention (V_{CC})	1.5V to 5.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V	Input Voltage (V_{IN})	0V to 5.5V
DC Input Diode Current (I_{IK})		Output Voltage (V_{OUT})	0V to V_{CC}
@ $V_{IN} < -0.5V$	-50 mA	Operating Temperature (T_A)	-40°C to +85°C
@ $V_{IN} > 6V$	+20 mA	Input Rise and Fall Time (t_r, t_f)	
DC Output Diode Current (I_{OK})		V_{CC} @ 1.8V, 2.5V ±0.2V	0 ns/V to 20 ns/V
@ $V_{OUT} < -0.5V$	-50 mA	V_{CC} @ 3.3V ± 0.3V	0 ns/V to 10 ns/V
@ $V_{OUT} > 6V, V_{CC} = GND$	+20 mA	V_{CC} @ 5.0V ± 0.5V	0 ns/V to 5 ns/V
DC Output Current (I_{OUT})	± 50 mA	Thermal Resistance (θ_{JA})	SC70-5 425°C/W
DC V_{CC}/GND Current (I_{CC}/I_{GND})	± 50 mA		
Storage Temperature (T_{STG})	-65°C to +150°C		
Junction Temperature under Bias (T_J)	150°C		
Junction Lead Temperature (T_L):			
(Soldering, 10 seconds)	260°C		
Power Dissipation (P_D) @ +85°C			
SC70-5	150 mW		

Absolute Maximum Ratings (Note 1)		Recommended Operating Conditions (Note 2)	
Supply Voltage (V_{CC})	-0.5V to +6.5V	Supply Voltage Operating (V_{CC})	1.85V to 5.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V	Supply Voltage Data Retention (V_{CC})	1.5V to 5.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V	Input Voltage (V_{IN})	0V to 5.5V
DC Input Diode Current (I_{IK})		Output Voltage (V_{OUT})	0V to V_{CC}
@ $V_{IN} < -0.5V$	-50 mA	Operating Temperature (T_A)	-40°C to +85°C
@ $V_{IN} > 6V$	+20 mA	Input Rise and Fall Time (t_r, t_f)	
DC Output Diode Current (I_{OK})		V_{CC} @ 1.8V, 2.5V ±0.2V	0 ns/V to 20 ns/V
@ $V_{OUT} < -0.5V$	-50 mA	V_{CC} @ 3.3V ± 0.3V	0 ns/V to 10 ns/V
@ $V_{OUT} > 6V, V_{CC} = GND$	+20 mA	V_{CC} @ 5.0V ± 0.5V	0 ns/V to 5 ns/V
DC Output Current (I_{OUT})	± 50 mA	Thermal Resistance (θ_{JA})	SC70-5 659°C/W
DC V_{CC}/GND Current (I_{CC}/I_{GND})	± 50 mA	MicroPak 382°C/W	
Storage Temperature (T_{STG})	-65°C to +150°C		
Junction Temperature under Bias (T_J)	150°C		
Junction Lead Temperature (T_L):			
(Soldering, 10 seconds)	260°C		
Power Dissipation (P_D) @ +85°C			
SC70-5	190 mW		
MicroPak	327 mW		

- Replaced SOT23 package with SC-74A.
- Adjusted Thermal Resistance to reflect new die.

Existing datasheet

θ_{JA}	Thermal Resistance	SOT-23		°C/W
		SC70-5	MicroPak™-6	
		300	435	
		500	500	
		560	560	

New

θ_{JA}	Thermal Resistance	SC-74A		°C/W
		SC70-5	MicroPak™-6	
		555	659	
		382	382	
		382	382	

- Adjusted High-Level Input Voltage and Low-Level Input Voltage to reflect new die.

Existing datasheet

V_{IH}	HIGH Level Input Voltage	1.65 to 1.95 2.30 to 5.50	$0.75V_{CC}$	$0.75V_{CC}$	V
V_{IL}	LOW Level Input Voltage	1.65 to 1.95 2.30 to 5.50	$0.25V_{CC}$ $0.30V_{CC}$	$0.25V_{CC}$ $0.30V_{CC}$	V

New

V_{IH}	HIGH Level Input Voltage	1.65 to 1.95 2.30 to 5.50	$0.65V_{CC}$	$0.65V_{CC}$	V
V_{IL}	LOW Level Input Voltage	1.65 to 1.95 2.30 to 5.50	$0.35V_{CC}$ $0.30V_{CC}$	$0.35V_{CC}$ $0.30V_{CC}$	V

V_{IH}	HIGH Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.75 V_{CC}$ $0.7 V_{CC}$	$0.75 V_{CC}$ $0.7 V_{CC}$	V
V_{IL}	LOW Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.25 V_{CC}$ $0.3 V_{CC}$	$0.25 V_{CC}$ $0.3 V_{CC}$	V

V_{IH}	HIGH Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.65 V_{CC}$ $0.7 V_{CC}$	$0.65 V_{CC}$ $0.7 V_{CC}$	V
V_{IL}	LOW Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.35 V_{CC}$ $0.3 V_{CC}$	$0.35 V_{CC}$ $0.3 V_{CC}$	V

- Positive Threshold Voltages adjusted to remove Minimum limits.
- Negative Threshold Voltages adjusted to remove Maximum limits.

Existing datasheet

Symbol	Parameter	V_{CC}	Conditions	$T_A=+25^\circ C$			$T_A=-40$ to $+85^\circ C$			Units
				Min.	Typ.	Max.	Min.	Max.		
V_P	Positive Threshold Voltage	1.65		0.60	0.99	1.40	0.60	1.40	V	
		2.30		1.00	1.39	1.80	1.00	1.80		
		3.00		1.30	1.77	2.20	1.30	2.20		
		4.50		1.90	2.49	3.10	1.90	3.10		
		5.50		2.20	2.95	3.60	2.20	3.60		
V_N	Negative Threshold Voltage	1.65		0.20	0.50	0.90	0.20	0.90	V	
		2.30		0.40	0.75	1.15	0.40	1.15		
		3.00		0.60	0.99	1.50	0.60	1.50		
		4.50		1.00	1.43	2.00	1.00	2.00		
		5.50		1.20	1.70	2.30	1.20	2.30		

New

Symbol	Parameter	V_{CC}	Conditions	$T_A=+25^\circ C$			$T_A=-40$ to $+85^\circ C$			Units
				Min.	Typ.	Max.	Min.	Max.		
V_P	Positive Threshold Voltage	1.65			0.99	1.40		1.40	V	
		2.30			1.39	1.80		1.80		
		3.00			1.77	2.20		2.20		
		4.50			2.49	3.10		3.10		
		5.50			2.95	3.60		3.60		
V_N	Negative Threshold Voltage	1.65		0.20	0.50		0.20		V	
		2.30		0.40	0.75		0.40			
		3.00		0.60	0.99		0.60			
		4.50		1.00	1.43		1.00			
		5.50		1.20	1.70		1.20			

Symbol	Parameter	V_{CC} (V)	Conditions	$T_A=+25^\circ C$			$T_A=-40$ to $+85^\circ C$			Units
				Min.	Typ.	Max.	Min.	Max.		
V_P	Positive Threshold Voltage	1.65		0.60	1.00	1.40	0.60	1.40	V	
		1.80		0.70	1.10	1.50	0.70	1.50		
		2.30		1.00	1.40	1.80	1.00	1.80		
		3.00		1.30	1.75	2.20	1.30	2.20		
		4.50		1.90	2.45	3.10	1.90	3.10		
V_N	Negative Threshold Voltage	1.65		0.20	0.50	0.80	0.20	0.80	V	
		1.80		0.25	0.55	0.90	0.25	0.90		
		2.30		0.40	0.75	1.15	0.40	1.15		
		3.00		0.60	1.00	1.50	0.60	1.50		
		4.50		1.00	1.43	2.00	1.00	2.00		
5.50		1.20	1.70	2.30	1.20	2.30				

Symbol	Parameter	V_{CC} (V)	Conditions	$T_A=+25^\circ C$			$T_A=-40$ to $+85^\circ C$			Units
				Min.	Typ.	Max.	Min.	Max.		
V_P	Positive Threshold Voltage	1.65			1.00	1.40		1.40	V	
		1.80			1.10	1.50		1.50		
		2.30			1.40	1.80		1.80		
		3.00			1.75	2.20		2.20		
		4.50			2.45	3.10		3.10		
V_N	Negative Threshold Voltage	1.65		0.20	0.50		0.20		V	
		1.80		0.25	0.55		0.25			
		2.30		0.40	0.75		0.40			
		3.00		0.60	1.00		0.60			
		4.50		1.00	1.43		1.00			
5.50		1.20	1.70		1.20					

- Input Leakage Current specification adjusted to remove crossover with Power Off Current Specification

Existing datasheet

I_{IN}	Input Leakage Current	0 to 5.5	$V_{IN}=5.5V, GND$	± 1	± 10	μA
I_{IN}	Input Leakage Current	0 to 5.5		± 1	± 10	μA

New

I_{IN}	Input Leakage Current	1.65 to 5.5	$V_{IN}=5.5V, GND$	± 1	± 10	μA
I_{IN}	Input Leakage Current	1.65 to 5.5		± 1	± 10	μA



- Removed Min limits from all Propagation Delay, Output Enable Time and Output Disable Time specifications.

Existing datasheet

New

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C			Units	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PHL} , t _{PLH}	Propagation Delay	1.85	C _L =15pF, R _D =1MΩ	2.0	5.4	11.4	2.0	12.0	ns	Figure 4 Figure 5	
		1.80		2.0	4.5	9.5	2.0	10.0			
		2.50 ± 0.20		0.8	3.0	6.5	0.8	7.0			
		3.30 ± 0.30		0.5	2.4	4.5	0.5	4.7			
		5.00 ± 0.50		0.5	2.0	3.9	0.5	4.1			
		3.30 ± 0.30 5.00 ± 0.50		C _L =50pF, R _D =500Ω	1.5	2.9	5.0	1.5			5.2
5.00 ± 0.50	0.8	2.4	4.3	0.8	4.5						

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C			Units	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PHL} , t _{PLH}	Propagation Delay	1.85	C _L =15pF, R _D =1MΩ		5.4	11.4		12.0	ns	Figure 4 Figure 5	
		1.80			4.5	9.5		10.0			
		2.50 ± 0.20			3.0	6.5		7.0			
		3.30 ± 0.30			2.4	4.5		4.7			
		5.00 ± 0.50			2.0	3.9		4.1			
		3.30 ± 0.30 5.00 ± 0.50		C _L =50pF, R _D =500Ω		2.9	5.0				5.2
5.00 ± 0.50			2.4	4.3		4.5					

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C			Units	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PLZ}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2V _{CC}	1.5	5.5	12.9	1.5	13.4	ns	Figure 4 Figure 5	
		1.80		1.5	4.6	10.5	1.5	11.0			
		2.50 ± 0.20		0.8	3.0	7.0	0.8	7.5			
		3.30 ± 0.30		0.8	2.4	5.0	0.8	5.2			
		5.00 ± 0.50		0.5	1.9	4.3	0.5	4.5			
		5.00 ± 0.50		1.5	5.0	12.9	1.5	13.4			
t _{PHZ}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2V _{CC}	1.5	4.1	10.5	1.5	11.0	ns	Figure 4 Figure 5	
		1.80		0.8	2.5	7.0	0.8	7.5			
		2.50 ± 0.20		0.8	2.1	5.0	0.8	5.2			
		3.30 ± 0.30		0.8	2.1	5.0	0.8	5.2			
		5.00 ± 0.50		0.5	1.2	4.3	0.5	4.5			
		5.00 ± 0.50		1.5	5.0	12.9	1.5	13.4			

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C			Units	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PLZ}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2V _{CC}		5.5	12.9		13.4	ns	Figure 4 Figure 5	
		1.80			4.6	10.5		11.0			
		2.50 ± 0.20			3.0	7.0		7.5			
		3.30 ± 0.30			2.4	5.0		5.2			
		5.00 ± 0.50			1.9	4.3		4.5			
		5.00 ± 0.50			5.0	12.9		13.4			
t _{PHZ}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2V _{CC}		4.1	10.5		11.0	ns	Figure 4 Figure 5	
		1.80			2.5	7.0		7.5			
		2.50 ± 0.20			2.1	5.0		5.2			
		3.30 ± 0.30			2.1	5.0		5.2			
		5.00 ± 0.50			1.2	4.3		4.5			
		5.00 ± 0.50			5.0	12.9		13.4			

Symbol	Parameter	V _{CC}	Condition	T _A =+25°C			T _A =-40 to +85°C			Unit	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PLH} , t _{PHL}	Propagation Delay A to Y ₀ or Y ₁	1.80 ± 0.15	C _L =15pF, R _D =500Ω, V _I =OPEN	2.0	6.3	10.1	2.0	10.5	ns	Figure 4 Figure 6	
		2.50 ± 0.20		1.0	3.6	5.7	1.0	6.0			
		3.30 ± 0.30		0.8	2.7	4.0	0.8	4.3			
		5.00 ± 0.50		0.5	2.0	3.1	0.5	3.3			
		3.30 ± 0.30		1.2	3.4	4.9	1.2	5.4			
		5.00 ± 0.50		0.8	2.5	3.9	0.8	4.2			
t _{PLZ} , t _{PHZ}	Output Enable Time	1.80 ± 0.15	C _L =50pF, R _D , R _O =500Ω, V _I =GND for t _{PLZ} , V _I =V _{IN} for t _{PHZ} , V _{IN} =2 x V _{CC}	3.0	6.9	12.0	3.0	12.5	ns	Figure 4 Figure 6	
		2.50 ± 0.20		1.8	4.2	6.8	1.8	7.3			
		3.30 ± 0.30		1.2	3.2	5.0	1.2	5.5			
		5.00 ± 0.50		0.8	2.5	4.0	0.8	4.3			
		1.80 ± 0.15		2.5	6.0	10.0	2.5	10.5			
		2.50 ± 0.20		1.5	4.0	6.8	1.5	7.1			
t _{PLZ} , t _{PHZ}	Output Disable Time	1.80 ± 0.15	C _L =50pF, R _D , R _O =500Ω, V _I =GND for t _{PLZ} , V _I =V _{IN} for t _{PHZ} , V _{IN} =2 x V _{CC}	0.8	2.9	4.9	0.8	5.3	ns	Figure 4 Figure 6	
		2.50 ± 0.20		0.3	1.8	3.5	0.3	3.7			
		3.30 ± 0.30									
		5.00 ± 0.50									
		1.80 ± 0.15		2.5	6.0	10.0	2.5	10.5			
		2.50 ± 0.20		1.5	4.0	6.8	1.5	7.1			

Symbol	Parameter	V _{CC}	Condition	T _A =+25°C			T _A =-40 to +85°C			Unit	Figure
				Min.	Typ.	Max.	Min.	Max.			
t _{PLH} , t _{PHL}	Propagation Delay A to Y ₀ or Y ₁	1.80 ± 0.15	C _L =15pF, R _D =500Ω, V _I =OPEN		6.3	10.1		10.5	ns	Figure 4 Figure 6	
		2.50 ± 0.20			3.6	5.7		6.0			
		3.30 ± 0.30			2.7	4.0		4.3			
		5.00 ± 0.50			2.0	3.1		3.3			
		3.30 ± 0.30			3.4	4.9		5.4			
		5.00 ± 0.50			2.5	3.9		4.2			
t _{PLZ} , t _{PHZ}	Output Enable Time	1.80 ± 0.15	C _L =50pF, R _D , R _O =500Ω, V _I =GND for t _{PLZ} , V _I =V _{IN} for t _{PHZ} , V _{IN} =2 x V _{CC}		6.9	12.0		12.5	ns	Figure 4 Figure 6	
		2.50 ± 0.20			4.2	6.8		7.3			
		3.30 ± 0.30			3.2	5.0		5.5			
		5.00 ± 0.50			2.5	4.0		4.3			
		1.80 ± 0.15			6.0	10.0		10.5			
		2.50 ± 0.20			4.0	6.8		7.1			
t _{PLZ} , t _{PHZ}	Output Disable Time	1.80 ± 0.15	C _L =50pF, R _D , R _O =500Ω, V _I =GND for t _{PLZ} , V _I =V _{IN} for t _{PHZ} , V _{IN} =2 x V _{CC}		2.9	4.9		5.3	ns	Figure 4 Figure 6	
		2.50 ± 0.20			1.8	3.5		3.7			
		3.30 ± 0.30									
		5.00 ± 0.50									
		1.80 ± 0.15			6.0	10.0		10.5			
		2.50 ± 0.20			4.0	6.8		7.1			

- Removed Min limits from all Propagation Delay, Output Enable Time and Output Disable Time specifications.

Existing datasheet

New

Symbol	Parameter	V _{CC} (V)	T _A = +25°C			T _A = -40°C to +85°C			Units	Conditions	Figure Number
			Min	Typ	Max	Min	Max				
t _{PLZ}	Propagation Delay D to Q	1.65	2.0	9.0	15.0	2.0	16.0	ns	C _L = 15 pF R _D = 1 MΩ S ₁ = Open	Figures 1, 3	
		1.8	2.0	6.1	10.0	2.0	10.5				
		2.5 ± 0.2	1.5	3.6	6.5	1.6	6.8				
		3.3 ± 0.3	1.0	2.7	4.6	1.2	5.0				
		5.0 ± 0.5	1.0	2.0	3.4	1.0	3.7				
		3.3 ± 0.3	1.5	3.3	5.5	1.5	6.2				
t _{PLH} , t _{PHL}	Propagation Delay LE to Q	1.65	2.0	9.0	14.5	2.0	15.0	ns	C _L = 50 pF, V _I = 2x V _{CC} R _D , R _O = 500Ω S ₁ = Open for t _{PLH} , S ₁ = V _I for t _{PHL}	Figures 1, 3	
		1.8	2.0	6.0	9.6	2.0	10.0				
		2.5 ± 0.2	1.8	3.5	6.1	1.5	6.6				
		3.3 ± 0.3	1.3	2.6	4.4	1.0	4.8				
		5.0 ± 0.5	1.0	2.0	3.2	0.8	3.5				
		3.3 ± 0.3	1.5	3.3	5.3	1.5	6.2				
t _{PLZ} , t _{PHZ}	Output Enable Time	1.65	2.0	9.0	13.5	2.0	14.6	ns	C _L = 50 pF, V _I = 2x V _{CC} R _D , R _O = 500Ω S ₁ = GND for t _{PHZ} , S ₁ = V _I for t _{PLZ}	Figures 1, 4	
		1.8	2.0	6.0	9.0	2.0	9.5				
		2.5 ± 0.2	2.0	3.7	6.0	1.8	6.6				
		3.3 ± 0.3	1.5	2.8	5.0	1.4	5.3				
		5.0 ± 0.5	1.0	2.2	3.7	1.0	3.9				
		3.3 ± 0.3	1.5	2.8	4.5	1.4	4.7				
t _{PLZ} , t _{PHZ}	Output Disable Time	1.65	2.0	7.7	12.0	2.0	13.0	ns	C _L = 50 pF, V _I = 2x V _{CC} R _D , R _O = 500Ω S ₁ = GND for t _{PHZ} , S ₁ = V _I for t _{PLZ}	Figures 1, 4	
		1.8	2.0	5.1	8.0	2.0	8.5				
		2.5 ± 0.2	2.0	3.5	6.0	1.8	6.3				
		3.3 ± 0.3	1.5	2.8	4.5	1.4	4.7				
		5.0 ± 0.5	1.0	2.3	3.7	1.0	3.9				
		3.3 ± 0.3	1.5	2.8	4.5	1.4	4.7				
t _S	Setup Time, D to LE	2.5 ± 0.2				2.0	ns	C _L = 50 pF R _D = 500 Ω, S ₁ = Open	Figures 1, 5		
		3.3 ± 0.3				1.5					
		5.0 ± 0.5				1.5					
t _H	Hold Time, D to LE	2.5 ± 0.2				1.5	ns	C _L = 50 pF R _D = 500 Ω, S ₁ = Open	Figures 1, 5		
		3.3 ± 0.3				1.5					
		5.0 ± 0.5				1.5					
t _W	Pulse Width, LE	2.5 ± 0.2				3.0	ns	C _L = 50 pF R _D = 500 Ω, S ₁ = Open	Figures 1, 5		
		3.3 ± 0.3				3.0					
		5.0 ± 0.5				3.0					

Symbol	Parameter	V _{CC} (V)	T _A = +25°C			T _A = -40°C to +85°C			Units	Conditions	Figure Number
			Min	Typ	Max	Min	Max				
t _{PLZ}	Propagation Delay D to Q	1.65		9.0	15.0		16.0	ns	C _L = 15 pF R _D = 1 MΩ S ₁ = Open	Figures 1, 3	
		1.8		6.1	10.0		10.5				
		2.5 ± 0.2		3.6	6.5		6.8				
		3.3 ± 0.3		2.7	4.6		5.0				
		5.0 ± 0.5		2.0	3.4		3.7				
		3.3 ± 0.3		3.3	5.5		6.2				
t _{PLH} , t _{PHL}	Propagation Delay LE to Q	1.65		9.0	14.5		15.0	ns	C _L = 50 pF, V _I = 2x V _{CC} R _D , R _O = 500Ω S ₁ = Open for t _{PLH} , S ₁ = V _I for t _{PHL}	Figures 1, 3	
		1.8		6.0	9.6		10.0				
		2.5 ± 0.2		3.5	6.1		6.6				
		3.3 ± 0.3		2.6	4.4		4.8				
		5.0 ± 0.5		2.0	3.2		3.5				
		3.3 ± 0.3		3.3	5.3		6.2				
t _{PLZ} , t _{PHZ}	Output Enable Time	1.65									

**List of Affected Parts:**

Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the [PCN Customized Portal](#).

NC7SZ04M5X

NC7SZU04M5X

NC7SZ02M5X

NC7SZ08M5X

NC7SZ14M5X

NC7SZ86M5X

NC7SZ125M5X

NC7SZ32M5X

NC7SZ05M5X

NC7SZ126M5X

NC7SZ00M5X

NC7SZ38M5X

Japanese translation of the notification starts here.
通知の日本語訳はここから始まります。

Note: The Japanese version is for reference only. In case of any differences between the English and Japanese version, the English version shall control.

注：日本語版は参照用です。英語版と日本語版の違いがある場合は、英語版が優先されます。



変更件名:	NC7SZXX ファミリー FPCN22057X および FPCN22090X についてのデータシートの更新	
発効日:	26 June 2019	
連絡先情報:	現地のオン・セミコンダクター営業所または <david.manley@onsemi.com>にお問い合わせください。	
通知種別:	本製品速報は通知目的のみのものです。オン・セミコンダクターは本製品速報の発行により本変更を実行します。	
変更カテゴリ:	<input type="checkbox"/> ウェハファブの変更 <input type="checkbox"/> アセンブリの変更 <input type="checkbox"/> 試験の変更 <input checked="" type="checkbox"/> その他 <u>データシートの変更</u>	
変更サブカテゴリ:	<input type="checkbox"/> 製造拠点の追加 <input type="checkbox"/> 材料の変更 <input checked="" type="checkbox"/> データシート/製品資料の変更 <input type="checkbox"/> 製造拠点の移転 <input type="checkbox"/> 製品仕様の変更 <input type="checkbox"/> 出荷/パッケージング/表記 <input type="checkbox"/> 製造プロセスの変更 <input type="checkbox"/> その他: _____	
影響を受ける拠点:	オン・セミコンダクター拠点: なし	外部製造工場 / 下請業者拠点: なし
説明および目的:	<p>本 PB は、NC7SZ ファミリー FPCN22057X および FPCN22090X についてのデータシートの変更をお客様にお知らせするものです。</p> <p>仕様および/または仕様条件の変更に関する新旧データシート間での比較を以下に示します。</p> <ul style="list-style-type: none"> 変更箇所は赤色の丸で囲まれています。 旧データシートから変更される項目は赤色でハイライトされています。 新データシートで対応する値は緑色でハイライトされています。 黄色の丸で囲んだ変更箇所は PCN の後に変更が必要であることがわかったものです <p>他にも、ファミリーに合わせて仕様フォーマットを表現するためにデータシートの整理と標準化したことによる変更があります。これらの変更は、以下のような形で行われます。</p> <ul style="list-style-type: none"> スペルなどの事務的なミスの訂正。 ファミリーの標準を作成するための書式設定。 新しいパッケージタイプの追加、および入手できなくなったパッケージの削除見込み。 	



- 推奨定格電圧を超えるリファレンスを訂正。

Existing datasheet

Description

The NC7SZXX is a single two-input NAND gate from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 6V, independent of V_{CC} operating voltage.

General Description

The NC7SZXX is a single 3-Input NAND Gate from Fairchild's Ultra High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 7V independent of V_{CC} operating voltage.

Description

The NC7SZXX is a single 2-Input NAND gate with open drain output stage from Fairchild's Ultra-High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 6V independent of V_{CC} operating voltage. The open drain output stage tolerates voltages up to 6V independent of V_{CC} when in the high impedance state.

- SOT23 パッケージを SC-74A に置き換え。

Existing datasheet

Ordering Information

Part Number	Top Mark	Package	Packing Method
NC7SZXXM5X	7Z00	5-Lead SOT23, JEDEC MO-178, 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	Z00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	YY	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	YY	6-Lead, MicroPak2™, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Ordering Information

Part Number	Operating Temperature	Top Mark	Eco Status	Package	Packing Method
NC7SZXXM5X	-40 to +85°C	7Z14	RoHS	5-Lead, SOT23, JEDEC MO-178, 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	-40 to +85°C	Z14	RoHS	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	-40 to +85°C	B6	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	-40 to +85°C	B6	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

New

Description

The NC7SZXX is a single two-input NAND gate from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V, independent of V_{CC} operating voltage.

General Description

The NC7SZXX is a single 3-Input NAND Gate from Fairchild's Ultra High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V independent of V_{CC} operating voltage.

Description

The NC7SZXX is a single 2-Input NAND gate with open drain output stage from Fairchild's Ultra-High Speed Series of TinyLogic®. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65V to 5.5V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0V. Inputs tolerate voltages up to 5.5V independent of V_{CC} operating voltage. The open drain output stage tolerates voltages up to 5.5V independent of V_{CC} when in the high impedance state.

New

Ordering Information

Part Number	Top Mark	Package	Packing Method
NC7SZXXM5X	7Z00	5-Lead SC-74A, 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	Z00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	YY	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	YY	6-Lead, MicroPak2™, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Ordering Information

Part Number	Operating Temperature	Top Mark	Eco Status	Package	Packing Method
NC7SZXXM5X	-40 to +85°C	7Z14	RoHS	5-Lead, SC-74A, 1.6mm	3000 Units on Tape & Reel
NC7SZXXP5X	-40 to +85°C	Z14	RoHS	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZXXL6X	-40 to +85°C	B6	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZXXFHX	-40 to +85°C	B6	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel



- 新規プロセスに合わせて絶対最大電圧を調整。

Existing datasheet

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Voltage (V_{IN})	-0.5V to +7.0V
DC Output Voltage (V_{OUT})	-0.5V to +7.0V

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.5	7.0	V
V_{IN}	DC Input Voltage	-0.5	7.0	V
V_{OUT}	DC Output Voltage	-0.5	7.0	V

New

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +6.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.5	6.5	V
V_{IN}	DC Input Voltage	-0.5	6.5	V
V_{OUT}	DC Output Voltage	-0.5	6.5	V

- SOT23 パッケージを SC-74A に置き換え。
- 新規のダイを反映するためにワット損を調整。
- 新規のダイを反映するために熱抵抗を調整。

Existing datasheet

P_D	Power Dissipation at +85°C	SOT-23		mW
		SC70-5	MicroPak™-6	
		200	150	
			130	
			120	

New

P_D	Power Dissipation at +85°C	SC-74A		mW
		SC70-5	MicroPak™-6	
		225	190	
			327	
			327	

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +6.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V
DC Input Diode Current (I_{IK})	
@ $V_{IN} < -0.5V$	-50 mA
@ $V_{IN} > 6V$	+20 mA
DC Output Diode Current (I_{OK})	
@ $V_{OUT} < -0.5V$	-50 mA
@ $V_{OUT} > 6V, V_{CC} = GND$	+20 mA
DC Output Current (I_{OCT})	+50 mA
DC V_{CC}/GND Current (I_{CC}/I_{GND})	±50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Junction Temperature under Bias (T_J)	150°C
Junction Lead Temperature (T_L): (Soldering, 10 seconds)	260°C
Power Dissipation (P_D) @ +85°C	150 mW

Recommended Operating Conditions (Note 2)

Supply Voltage Operating (V_{CC})	1.65V to 5.5V
Supply Voltage Data Retention (V_{CC})	1.5V to 5.5V
Input Voltage (V_{IN})	0V to 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
$V_{CC} @ 1.8V, 2.5V \pm 0.2V$	0 ns/V to 20 ns/V
$V_{CC} @ 3.3V \pm 0.3V$	0 ns/V to 10 ns/V
$V_{CC} @ 5.0V \pm 0.5V$	0 ns/V to 5 ns/V
Thermal Resistance (θ_{JA})	425°C/W

Note 1: Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. The datasheet specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside datasheet specifications.
Note 2: Unused inputs must be held HIGH or LOW. They may not float.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +6.5V
DC Input Voltage (V_{IN})	-0.5V to +6.5V
DC Output Voltage (V_{OUT})	-0.5V to +6.5V
DC Input Diode Current (I_{IK})	
@ $V_{IN} < -0.5V$	-50 mA
@ $V_{IN} > 6V$	+20 mA
DC Output Diode Current (I_{OK})	
@ $V_{OUT} < -0.5V$	-50 mA
@ $V_{OUT} > 6V, V_{CC} = GND$	+20 mA
DC Output Current (I_{OCT})	±50 mA
DC V_{CC}/GND Current (I_{CC}/I_{GND})	±50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Junction Temperature under Bias (T_J)	150°C
Junction Lead Temperature (T_L): (Soldering, 10 seconds)	260°C
Power Dissipation (P_D) @ +85°C	190 mW
MicroPak	327 mW

Recommended Operating Conditions (Note 2)

Supply Voltage Operating (V_{CC})	1.65V to 5.5V
Supply Voltage Data Retention (V_{CC})	1.5V to 5.5V
Input Voltage (V_{IN})	0V to 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
$V_{CC} @ 1.8V, 2.5V \pm 0.2V$	0 ns/V to 20 ns/V
$V_{CC} @ 3.3V \pm 0.3V$	0 ns/V to 10 ns/V
$V_{CC} @ 5.0V \pm 0.5V$	0 ns/V to 5 ns/V
Thermal Resistance (θ_{JA})	659°C/W
MicroPak	382°C/W

Note 1: Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. The datasheet specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside datasheet specifications.
Note 2: Unused inputs must be held HIGH or LOW. They may not float.

- SOT23 パッケージを SC-74A に置き換え。
- 新規のダイを反映するために熱抵抗を調整。

Existing datasheet

θ_{JA}	Thermal Resistance	SOT-23		°C/W
		SC70-5	MicroPak™-6	
		300	435	
			500	
			560	

New

θ_{JA}	Thermal Resistance	SC-74A		°C/W
		SC70-5	MicroPak™-6	
		555	659	
			382	
			382	



- Hレベル入力電圧およびLレベル入力電圧を、新規のダイを反映するためにHレベル入力電圧およびLレベル入力電圧を調整。

Existing datasheet

V_{IH}	HIGH Level Input Voltage	1.65 to 1.95		$0.75V_{CC}$		$0.75V_{CC}$		V
V_{IL}	LOW Level Input Voltage	1.65 to 1.95		$0.25V_{CC}$		$0.25V_{CC}$		V

New

V_{IH}	HIGH Level Input Voltage	1.65 to 1.95		$0.65V_{CC}$		$0.65V_{CC}$		V
V_{IL}	LOW Level Input Voltage	1.65 to 1.95		$0.35V_{CC}$		$0.35V_{CC}$		V

V_{IH}	HIGH Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.75V_{CC}$		$0.75V_{CC}$		V
V_{IL}	LOW Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.25V_{CC}$		$0.25V_{CC}$		V

V_{IH}	HIGH Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.65V_{CC}$		$0.65V_{CC}$		V
V_{IL}	LOW Level Input Voltage	1.8 ± 0.15 2.3 to 5.5	$0.35V_{CC}$		$0.35V_{CC}$		V

- Positive Threshold voltage の下限を削除。
- Negative Threshold voltage の上限を削除。

Existing datasheet

Symbol	Parameter	V_{CC}	Conditions	$T_A=+25^\circ\text{C}$			$T_A=-40$ to $+85^\circ\text{C}$		Units
				Min.	Typ.	Max.	Min.	Max.	
V_P	Positive Threshold Voltage	1.65		0.60	0.99	1.40	0.60	1.40	V
		2.30		1.00	1.39	1.80	1.00	1.80	
		3.00		1.30	1.77	2.20	1.30	2.20	
		4.50		1.90	2.49	3.10	1.90	3.10	
		5.50		2.20	2.95	3.60	2.20	3.60	
V_N	Negative Threshold Voltage	1.65		0.20	0.50	0.90	0.20	0.90	V
		2.30		0.40	0.75	1.15	0.40	1.15	
		3.00		0.60	0.99	1.50	0.60	1.50	
		4.50		1.00	1.43	2.00	1.00	2.00	
		5.50		1.20	1.70	2.30	1.20	2.30	

New

Symbol	Parameter	V_{CC}	Conditions	$T_A=+25^\circ\text{C}$			$T_A=-40$ to $+85^\circ\text{C}$		Units
				Min.	Typ.	Max.	Min.	Max.	
V_P	Positive Threshold Voltage	1.65		0.99	1.40				V
		2.30		1.39	1.80				
		3.00		1.77	2.20				
		4.50		2.49	3.10				
		5.50		2.95	3.60				
V_N	Negative Threshold Voltage	1.65		0.20	0.50		0.20		V
		2.30		0.40	0.75		0.40		
		3.00		0.60	0.99		0.60		
		4.50		1.00	1.43		1.00		
		5.50		1.20	1.70		1.20		

Symbol	Parameter	V_{CC} (V)	Conditions	$T_A=+25^\circ\text{C}$			$T_A=-40$ to $+85^\circ\text{C}$		Units
				Min.	Typ.	Max.	Min.	Max.	
V_P	Positive Threshold Voltage	1.65		0.60	1.00	1.40	0.60	1.40	V
		1.80		0.70	1.10	1.50	0.70	1.50	
		2.30		1.00	1.40	1.80	1.00	1.80	
		3.00		1.30	1.75	2.20	1.30	2.20	
		4.50		1.90	2.45	3.10	1.90	3.10	
V_N	Negative Threshold Voltage	1.65		0.20	0.50	0.80	0.20	0.80	V
		1.80		0.25	0.55	0.90	0.25	0.90	
		2.30		0.40	0.75	1.15	0.40	1.15	
		3.00		0.60	1.00	1.50	0.60	1.50	
		4.50		1.00	1.43	2.00	1.00	2.00	
5.50		1.20	1.70	2.30	1.20	2.30			

Symbol	Parameter	V_{CC} (V)	Conditions	$T_A=+25^\circ\text{C}$			$T_A=-40$ to $+85^\circ\text{C}$		Units
				Min.	Typ.	Max.	Min.	Max.	
V_P	Positive Threshold Voltage	1.65			1.00	1.40		1.40	V
		1.80			1.10	1.50		1.50	
		2.30			1.40	1.80		1.80	
		3.00			1.75	2.20		2.20	
		4.50			2.45	3.10		3.10	
V_N	Negative Threshold Voltage	1.65		0.20	0.50		0.20	V	
		1.80		0.25	0.55		0.25		
		2.30		0.40	0.75		0.40		
		3.00		0.60	1.00		0.60		
		4.50		1.00	1.43		1.00		
5.50		1.20	1.70		1.20				

- 電源オフ電流仕様でクロスオーバーを除去したのに合わせて入力リーク電流仕様を調整

Existing datasheet

I_{IN}	Input Leakage Current	0 to 5.5	$V_{IN}=5.5\text{V, GND}$		± 1	± 10	μA
----------	-----------------------	----------	---------------------------	--	---------	----------	---------------

New

I_{IN}	Input Leakage Current	1.65 to 5.5	$V_{IN}=5.5\text{V, GND}$		± 1	± 10	μA
----------	-----------------------	-------------	---------------------------	--	---------	----------	---------------

I_{IN}	Input Leakage Current	0 to 5.5		± 1		± 10	μA	$V_{IN}=5.5\text{V, GND}$
----------	-----------------------	----------	--	---------	--	----------	---------------	---------------------------

I_{IN}	Input Leakage Current	1.65 to 5.5		± 1		± 10	μA	$V_{IN}=5.5\text{V, GND}$
----------	-----------------------	-------------	--	---------	--	----------	---------------	---------------------------

すべての伝播遅延と出力カインエール時間と出力ディセーブル時間の仕様から下限を削除

Existing datasheet

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C		Units	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PHL} , t _{PLH}	Propagation Delay	1.85	C _L =15pF, R _D =1MΩ	2.0	5.4	11.4	2.0	12.0	ns	Figure 4 Figure 5
		1.80		2.0	4.5	9.5	2.0	10.0		
		2.50 ± 0.20		0.8	3.0	6.5	0.8	7.0		
		3.30 ± 0.30		0.5	2.4	4.5	0.5	4.7		
		5.00 ± 0.50		0.5	2.0	3.9	0.5	4.1		
		5.00 ± 0.50		0.8	2.4	4.3	0.8	4.5		

New

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C		Units	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PHL} , t _{PLH}	Propagation Delay	1.85	C _L =15pF, R _D =1MΩ	5.4	11.4	12.0	2.0	12.0	ns	Figure 4 Figure 5
		1.80		4.5	9.5	10.0	2.0	10.0		
		2.50 ± 0.20		3.0	6.5	7.0	0.8	7.0		
		3.30 ± 0.30		2.4	4.5	4.7	0.5	4.7		
		5.00 ± 0.50		2.0	3.9	4.1	0.5	4.1		
		5.00 ± 0.50		2.9	5.0	5.2	0.8	5.2		

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C		Units	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PZL}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2×V _{CC}	1.5	5.5	12.9	1.5	13.4	ns	Figure 4 Figure 5
		1.80		1.5	4.6	10.5	1.5	11.0		
		2.50 ± 0.20		0.8	3.0	7.0	0.8	7.5		
		3.30 ± 0.30		0.8	2.4	5.0	0.8	5.2		
		5.00 ± 0.50		0.5	1.9	4.3	0.5	4.5		
		5.00 ± 0.50		1.5	5.0	12.9	1.5	13.4		

Symbol	Parameter	V _{CC}	Conditions	T _A =+25°C			T _A =-40 to +85°C		Units	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PZL}	Propagation Delay	1.85	C _L =50pF, R _D =500Ω, V _{IN} =2×V _{CC}	5.5	12.9	13.4	1.5	13.4	ns	Figure 4 Figure 5
		1.80		4.6	10.5	11.0	1.5	11.0		
		2.50 ± 0.20		3.0	7.0	7.5	0.8	7.5		
		3.30 ± 0.30		2.4	5.0	5.2	0.8	5.2		
		5.00 ± 0.50		1.9	4.3	4.5	0.5	4.5		
		5.00 ± 0.50		5.0	12.9	13.4	1.5	13.4		

Symbol	Parameter	V _{CC}	Condition	T _A =+25°C			T _A =-40 to +85°C		Unit	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PLH} , t _{PHL}	Propagation Delay A to Y ₀ or Y ₁	1.80 ± 0.15	C _L =15pF, R _O =1MΩ, V _I =OPEN	2.0	6.3	10.1	2.0	10.5	ns	Figure 4 Figure 6
		2.50 ± 0.20		1.0	3.6	5.7	1.0	6.0		
		3.30 ± 0.30		0.8	2.7	4.0	0.8	4.3		
		5.00 ± 0.50		0.5	2.0	3.1	0.5	3.3		
		3.30 ± 0.30		1.2	3.4	4.9	1.2	5.4		
		5.00 ± 0.50		0.8	2.5	3.9	0.8	4.2		

Symbol	Parameter	V _{CC}	Condition	T _A =+25°C			T _A =-40 to +85°C		Unit	Figure
				Min.	Typ.	Max.	Min.	Max.		
t _{PLH} , t _{PHL}	Propagation Delay A to Y ₀ or Y ₁	1.80 ± 0.15	C _L =15pF, R _O =500Ω, V _I =OPEN	6.3	10.1	10.5	2.0	10.5	ns	Figure 4 Figure 6
		2.50 ± 0.20		3.6	5.7	6.0	1.0	6.0		
		3.30 ± 0.30		2.7	4.0	4.3	0.8	4.3		
		5.00 ± 0.50		2.0	3.1	3.3	0.5	3.3		
		3.30 ± 0.30		1.2	3.4	4.9	1.2	5.4		
		5.00 ± 0.50		2.5	3.9	4.2	0.8	4.2		

すべての伝播遅延と出力カインエール時間と出力ディセーブル時間の仕様から下限を削除

Existing datasheet

Symbol	Parameter	V _{CC} (V)	T _A =+25°C			T _A =-40°C to +85°C		Units	Conditions	Figure Number
			Min	Typ	Max	Min	Max			
t _{PLH} , t _{PHL}	Propagation Delay D to Q	1.65	2.0	9.0	15.0	2.0	16.0	ns	C _L = 15 pF R _D = 1 MΩ S ₁ = Open	Figures 1, 3
		1.8	2.0	6.1	10.0	2.0	10.5			
		2.5±0.2	1.5	3.6	6.5	1.6	6.8			
		3.3±0.3	1.0	2.7	4.6	1.2	5.0			
		5.0±0.5	1.0	2.0	3.4	1.0	3.7			
		5.0±0.5	1.5	3.3	5.5	1.5	6.2			

New

Symbol	Parameter	V _{CC} (V)	T _A =+25°C			T _A =-40°C to +85°C		Units	Conditions	Figure Number
			Min	Typ	Max	Min	Max			
t _{PLH} , t _{PHL}	Propagation Delay D to Q	1.65	9.0	15.0	16.0	2.0	16.0	ns	C _L = 15 pF R _D = 1 MΩ S ₁ = Open	Figures 1, 3
		1.8	6.1	10.0	10.5	2.0	10.5			
		2.5±0.2	3.6	6.5	6.8	1.6	6.8			
		3.3±0.3	2.7	4.6	5.0	1.2	5.0			
		5.0±0.5	2.0	3.4	3.7	1.0	3.7			
		5.0±0.5	3.3	5.5	6.2	1.5	6.2			

**影響を受ける部品の一覧:**

注: 標準の部品番号(既製品)のみが部品一覧に記載されます。本 PCN に影響を受けるカスタム 部品は、PCN メールのお客様の特定の PCN の付属文書、または PCN カスタマイズポータルに記載されています。

NC7SZ04M5X

NC7SZU04M5X

NC7SZ02M5X

NC7SZ08M5X

NC7SZ14M5X

NC7SZ86M5X

NC7SZ125M5X

NC7SZ32M5X

NC7SZ05M5X

NC7SZ126M5X

NC7SZ00M5X

NC7SZ38M5X